Goddard Space Flight Center

National Aeronautics and Space Administration

Evaluation of Vertical Cavity Surface Emitting Lasers (VCSEL) mounted on CVD Diamond Substrates

NASA/GSFC Component Technology and Radiation Effects Branch

September 21, 2001

Contact: Melanie Ott, **Sigma Research and Engineering, (301)-286-0127**
Harry Shaw, NASA/GSFC, 301-286-6616

Introduction

This report summarizes the evaluation of 850 nm VCSELs manufactured by Emcore. The purpose of the evaluation was determine if the superior thermal properties of diamond as a substrate would improve the performance and reliability of the mounted VCSELs. Four VCSELs were mounted to diamond substrates and four more were mounted directly to Kovar headers and subjected accelerated voltage and current overdrive conditions. The diamond substrates provided a significant reliability advantage, however, there were unexplained shifts in the spectral properties of the devices. These mode shifts could be the subject of further investigation.

Bare die were purchased and mounted onto gold plated CVD diamond substrates 500um in thickness. Die attach was performed using 84-1 conductive epoxy (Ablestik). 1 mil Au thermosonic wire bonding was used. The individual die were mounted on 250 um centers. The substrates were mounted onto TO-8 gold plated kovar headers. A MTP ribbon cable was used as a waveguide to the HP7095 Optical Spectrum Analyzer (OSA) and HP 8153 Lightwave Multimeters.

4 VCSELs were mounted directly on the TO-8 cans to permit comparison of the performance with and without diamond substrates. Due to alignment fiber-VCSEL alignment difficulties, mating and demating of the ribbon cable was kept to a minimum.

Figures 1 and 2 depict the VCSELs unmounted and mounted on diamond. The devices used in the evaluation are no longer available as discrete parts. The next generation is preferred because the devices are available as monolithic arrays. The arrays are preferred because the optical alignment problems with the discrete devices can be eliminated. Figure 2a depicts the bare diamond substrate. Figure 2b is a block diagram of the test setup.

Figure 1. 850 nm VCSEL with 3 apertures

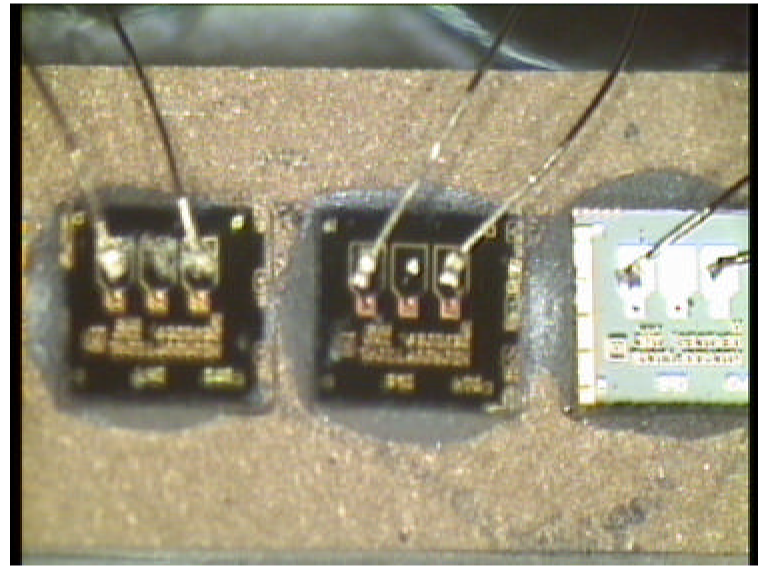

Figure 2. VCSELs mounted to CVD diamond substrates.

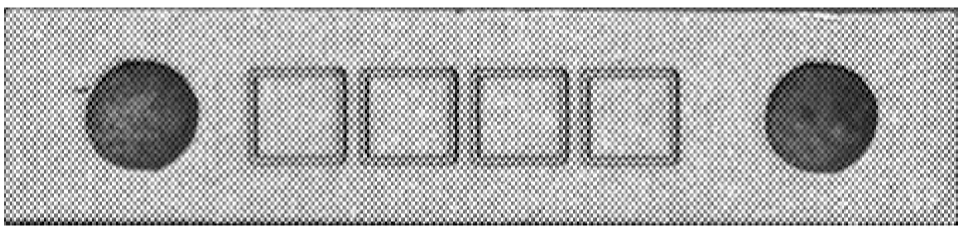

Figure 2a. Bare diamond substrate. Metalization is Ti/Pt/Au. Dimensions: 0.256” x 0.06” x 0.017” (thickness)

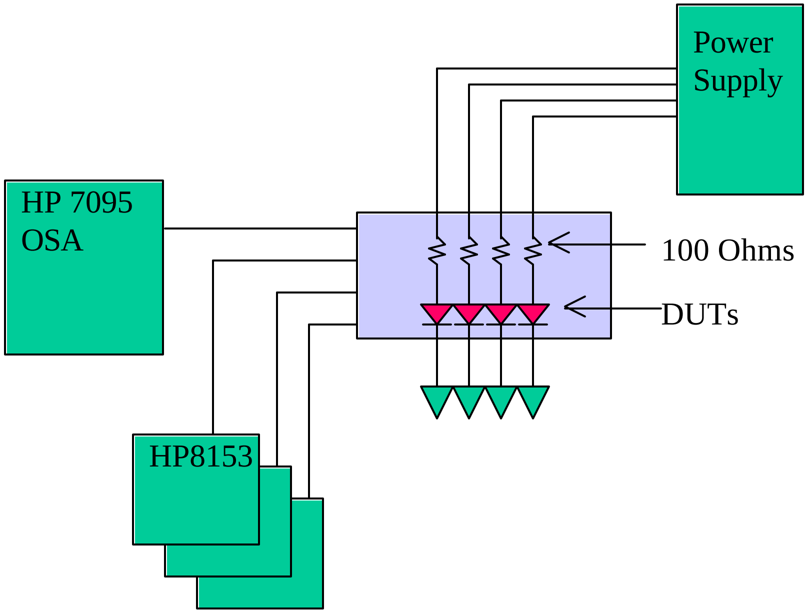

Figure 2b. Electrical Test Block Diagram

1. VCSEL Optical output power vs bias

Each of the 4 VCSELs are driven by single power supply through a 100 ohm resistor. Table 1 depicts the power output response of the a typical device under swept bias. This device is mounted directly to the TO-8 can

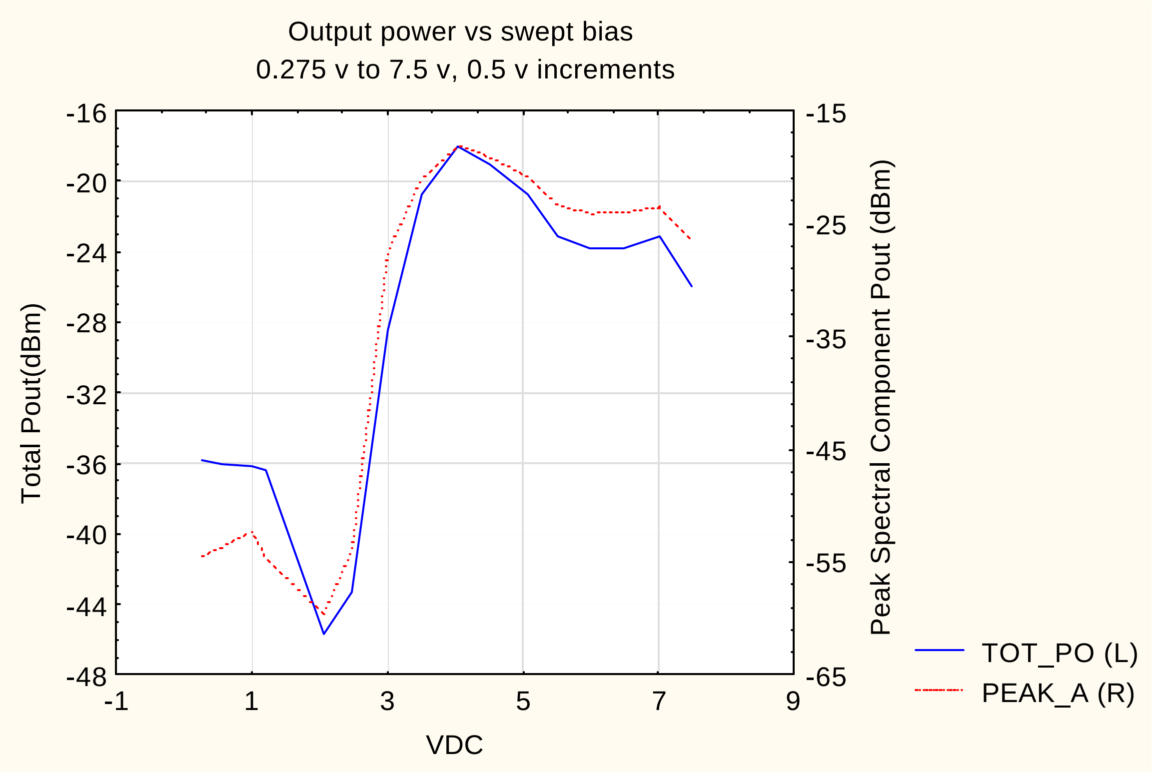

Table 1

PEAK_A is the power of the highest spectral output component. TOT_PO is the sum of the power of all the spectral components. The detected power is less than the actual power due to fiber-VCSEL misalignment. It is interesting to note that divergence of the two curves at the low and high ends of the bias conditions

2. Characteristics of the VCSEL-on-diamond.

The following charts summarize the 41 days of continuous monitoring of the VCSEL-on-diamond units. One of the 4 devices (VCSEL_1) was monitored by the OSA. The other 3 devices (VCSEL_2, _5, _8) were monitored the lightwave multimeter. For the latter devices, the only parameter recorded by the LABVIEW program is total power out. The summary of the raw power out numbers is shown in Table 2

Statistical Summary of Raw Power Output Data (dBm) for VCSEL_1
Table 2

5 V bias

	Observations	Mean Pout	Minimum Pout	Maximum Pout	Std.Dev.
VCSEL_1	674	-17.6358	-18.5157	-16.9374	.284717
VCSEL_5	674	-7.7309	-8.3565	-7.4715	.084840
VCSEL_2	674	-6.4325	-6.8194	-6.0730	.194107
VCSEL_8	674	-8.4453	-8.6328	-8.2102	.114320

6.25 V bias

	Observations	Mean Pout	Minimum Pout	Maximum Pout	Std.Dev.
VCSEL_1	913	-20.3849	-21.0891	-19.7740	.155107
VCSEL_5	913	-9.5464	-9.8297	-9.3930	.059760
VCSEL_2	913	-8.4815	-8.7290	-8.0134	.126077
VCSEL_8	913	-9.1052	-9.4310	-8.6967	.144907

7.5 V bias

	Observations	Mean Pout	Minimum Pout	Maximum Pout	Std.Dev.
VCSEL_1	387	-23.5835	-24.8671	-22.7887	.498200
VCSEL_5	387	-11.8555	-12.2915	-11.5739	.123101
VCSEL_2	387	-12.3018	-12.9328	-11.9314	.156877
VCSEL_8	387	-11.4199	-12.1042	-10.9691	.199144

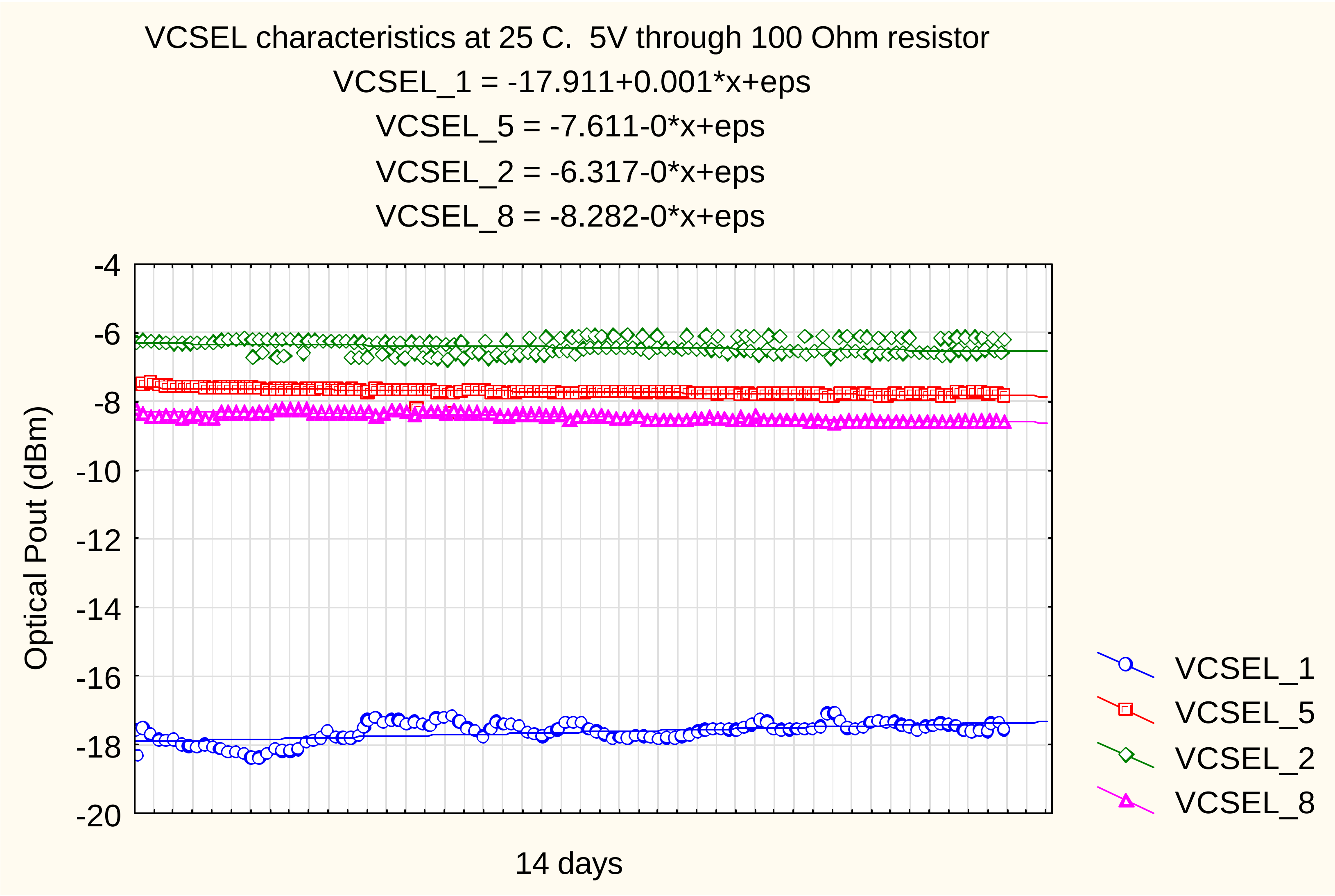

Figure 3. 5 V VCSEL data

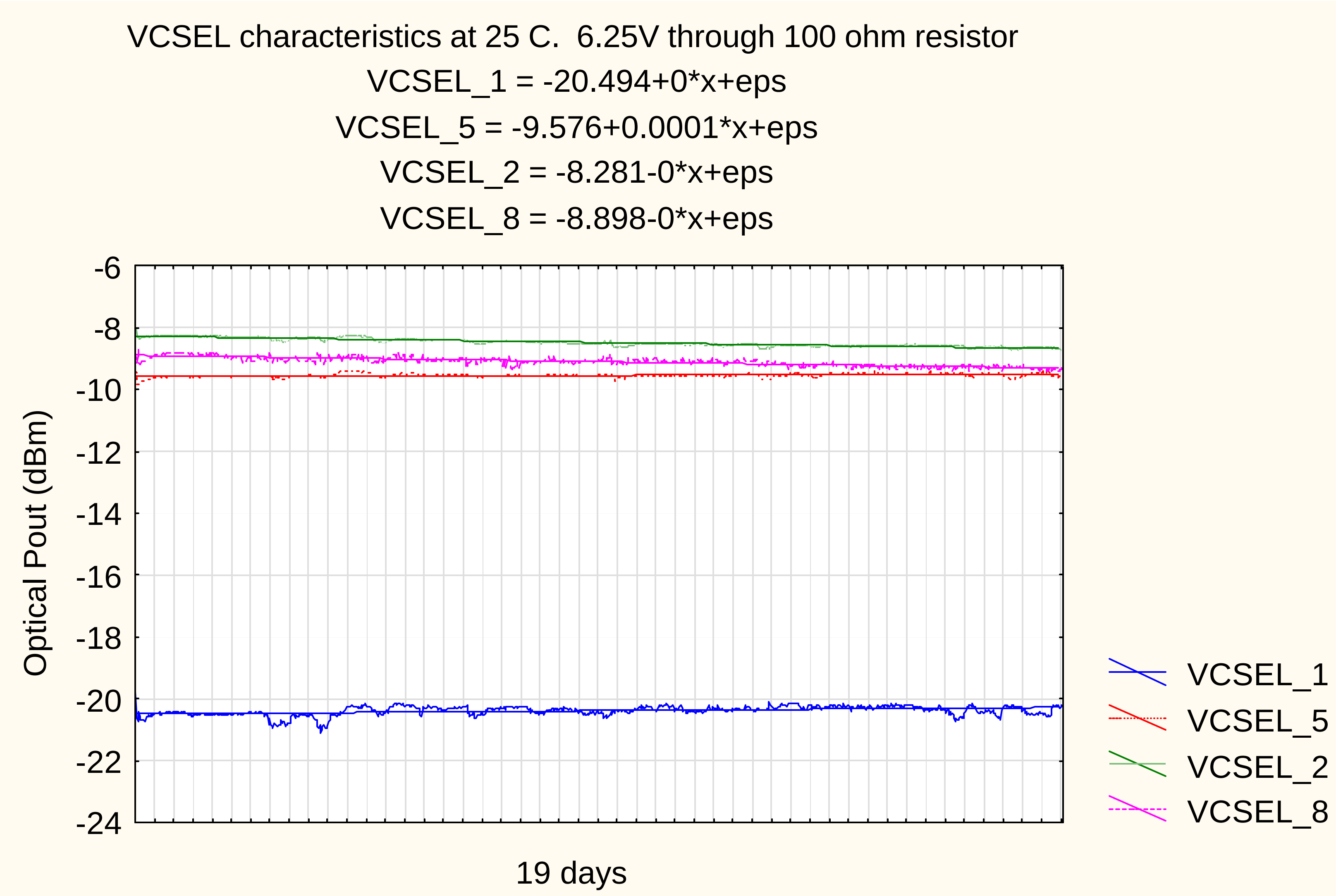

Figure 4. 6.25V VCSEL data

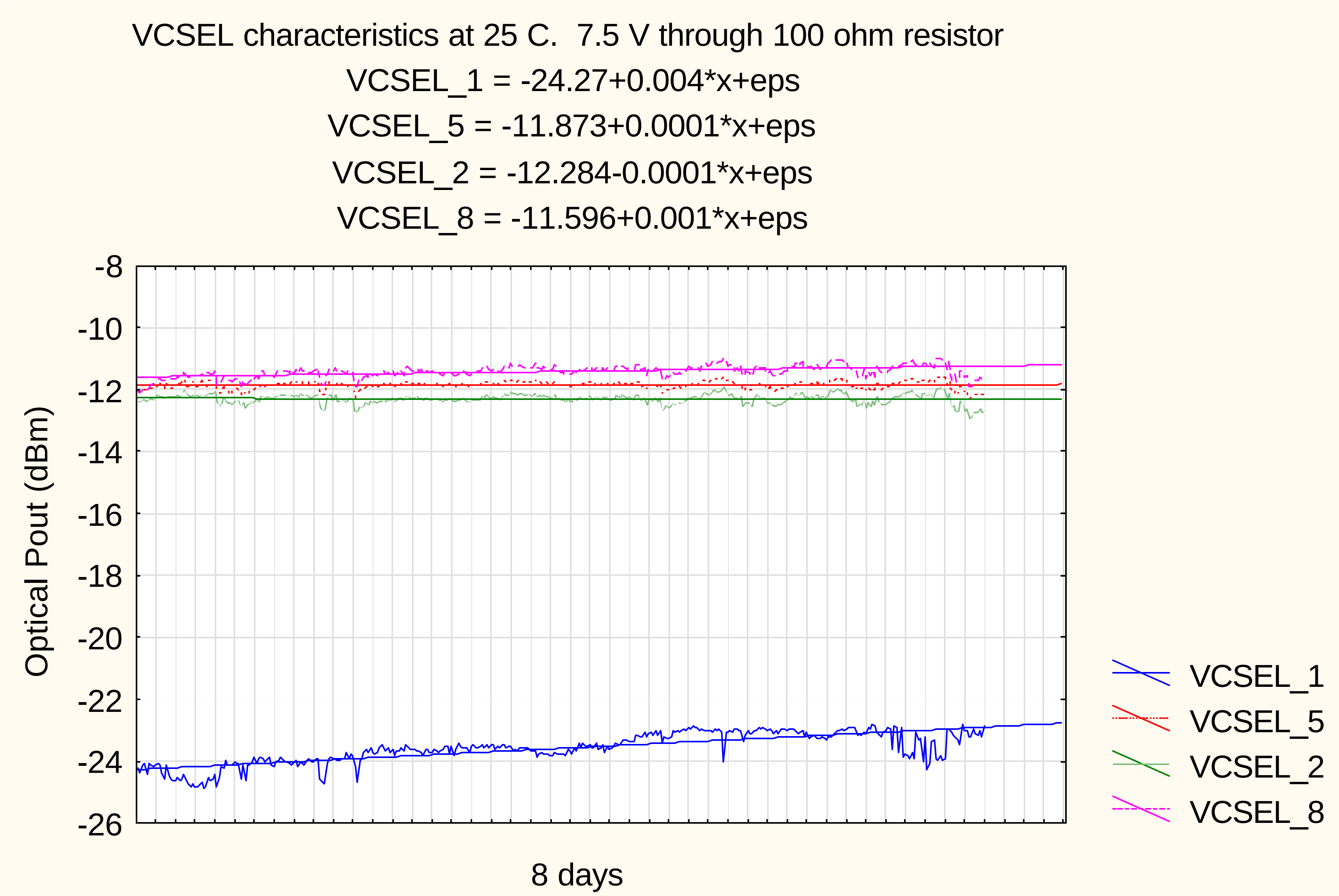

Figure 6. 7.5 V VCSEL data

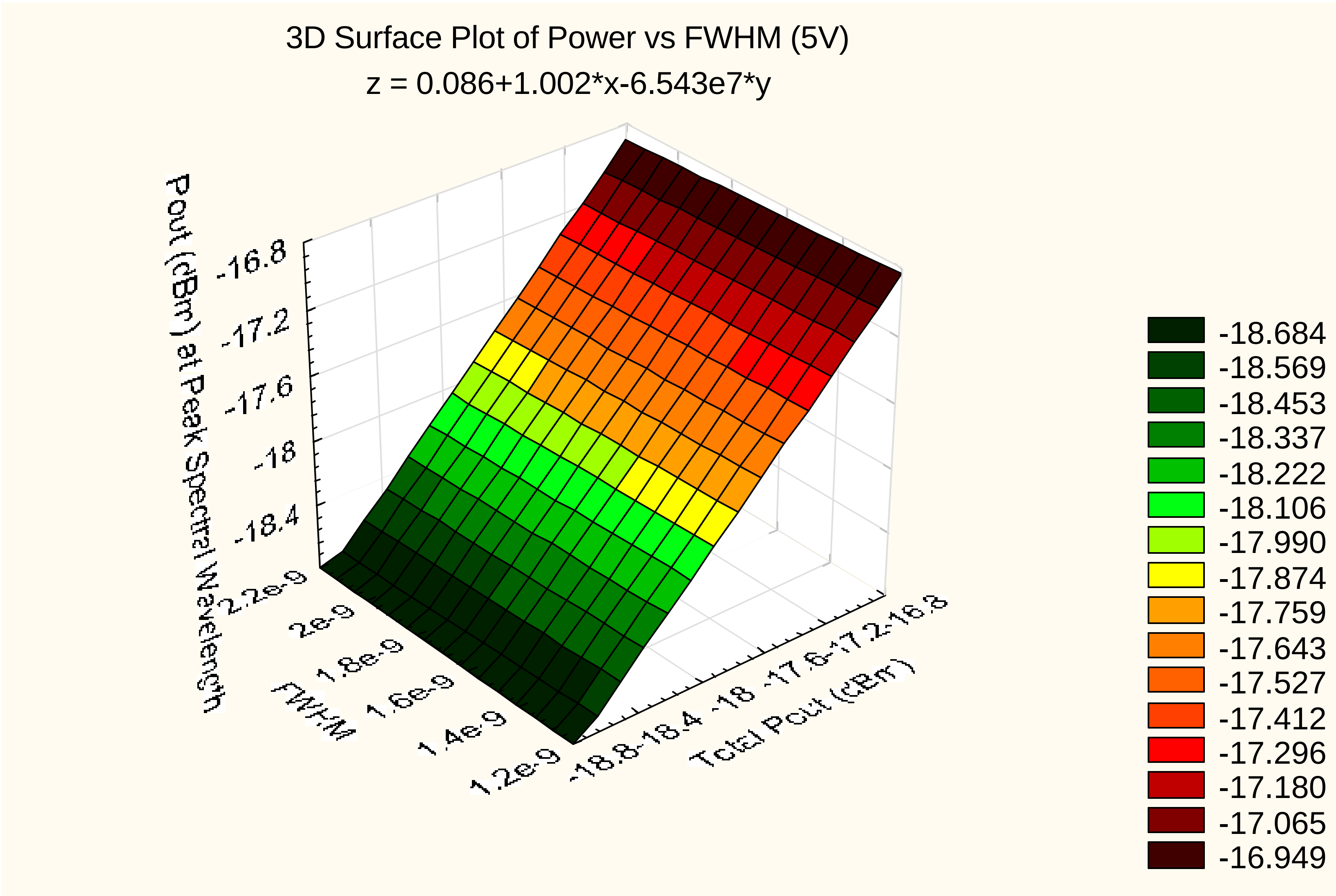

Figure 7. 3D Surface Plot of Power vs FHWM (5V)

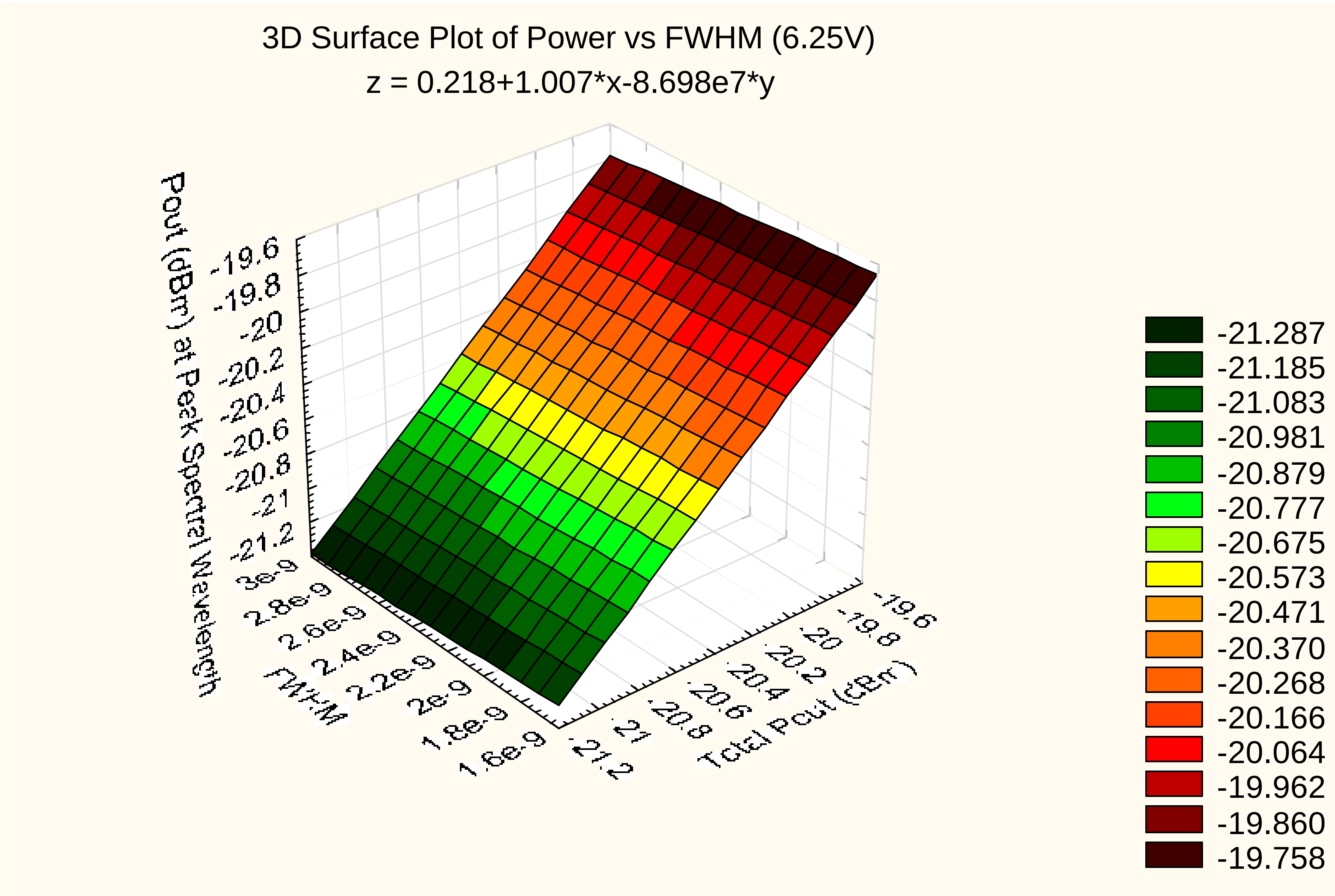

Figure 8. 3D Surface Plot of Power vs FHWM (6.25V)

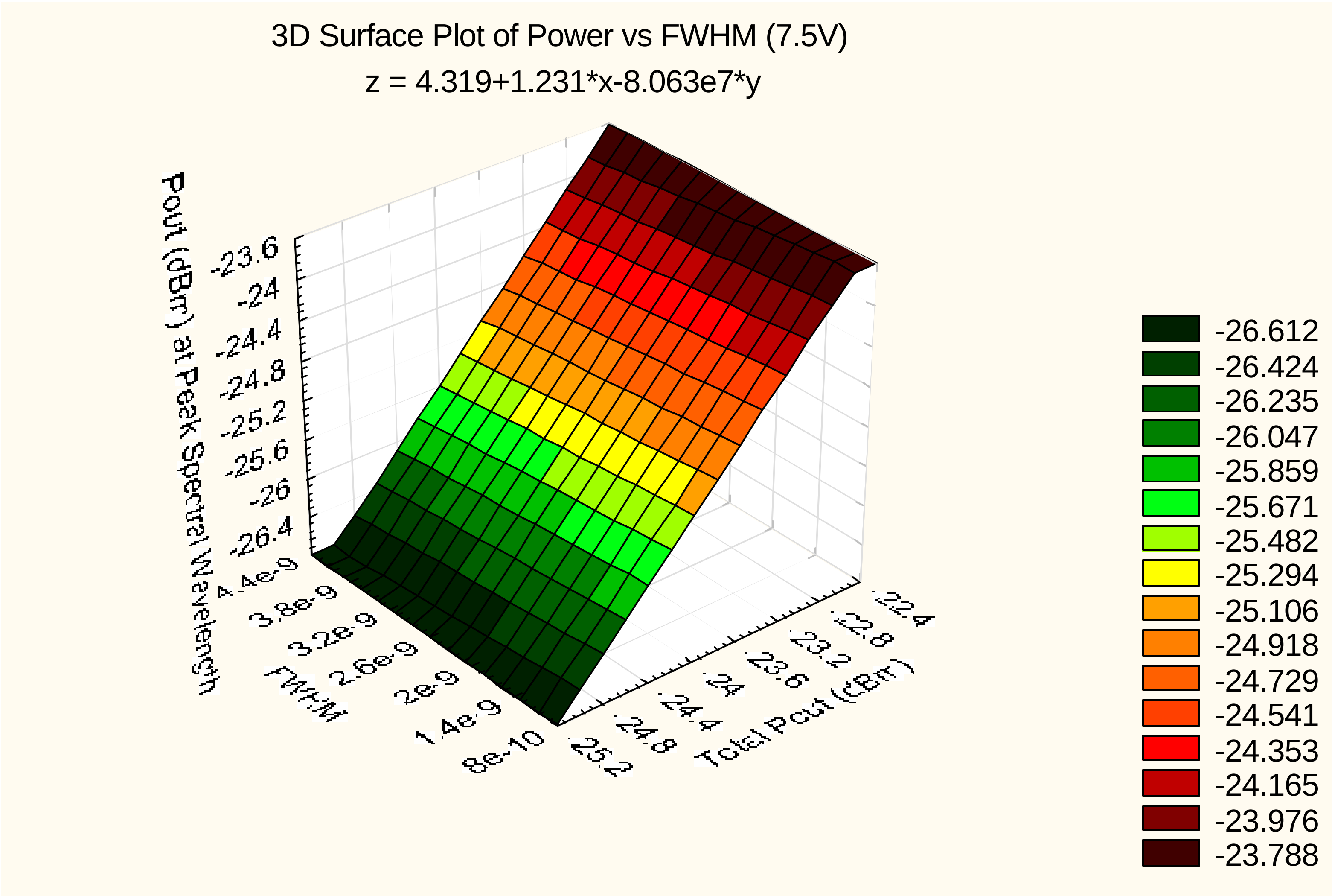

Figure 9. 3D Surface Plot of Power vs FHWM (7.5V)

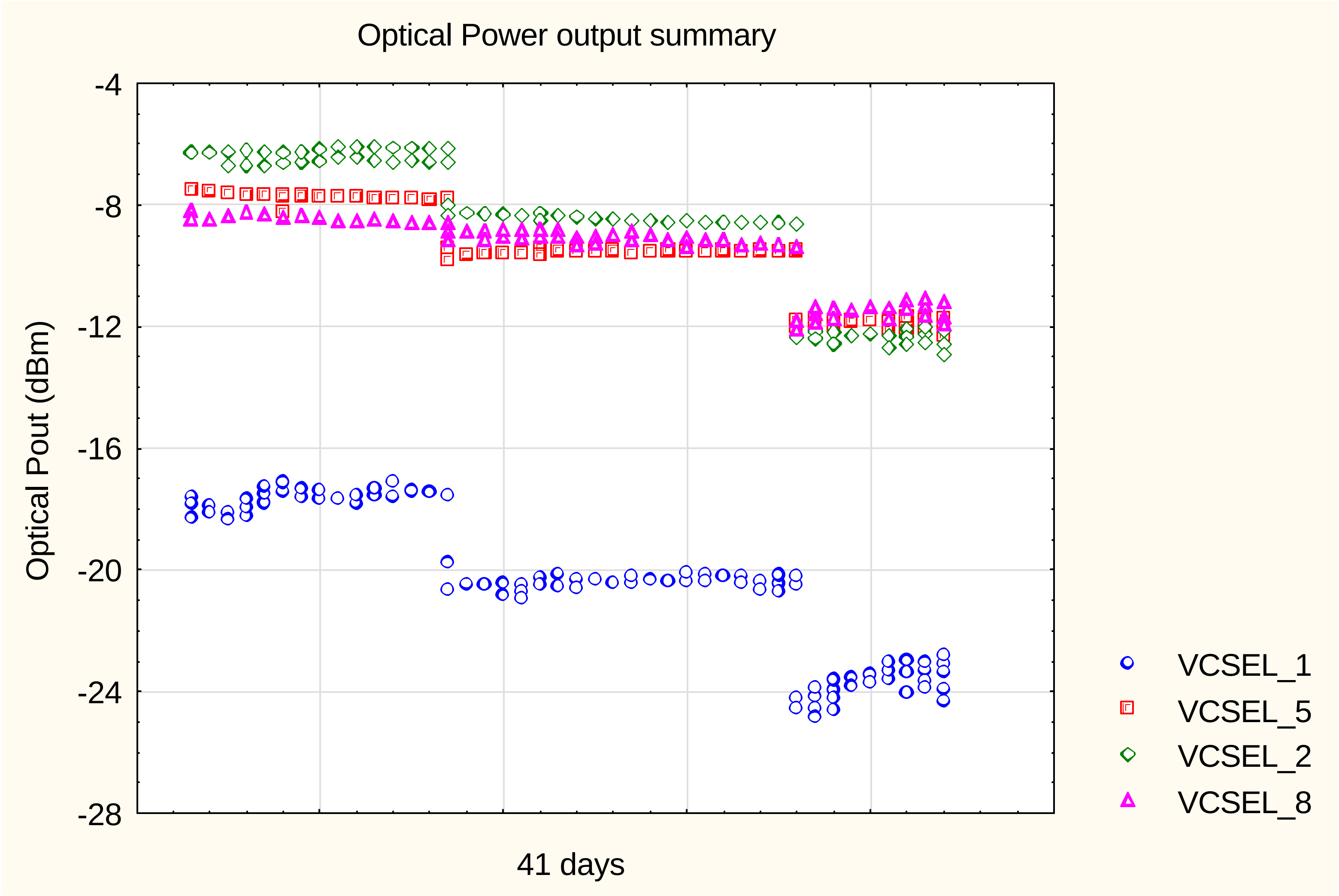

Figure 10. Optical Power output summary

3. Characteristics of the VCSELs mounted directly to Kovar headers.

The VCSELs mounted directly to the Kovar headers exhibited a power slump over time. After 2 days at 6.25 V, all 4 devices stopped exhibiting any power output at 850nm.

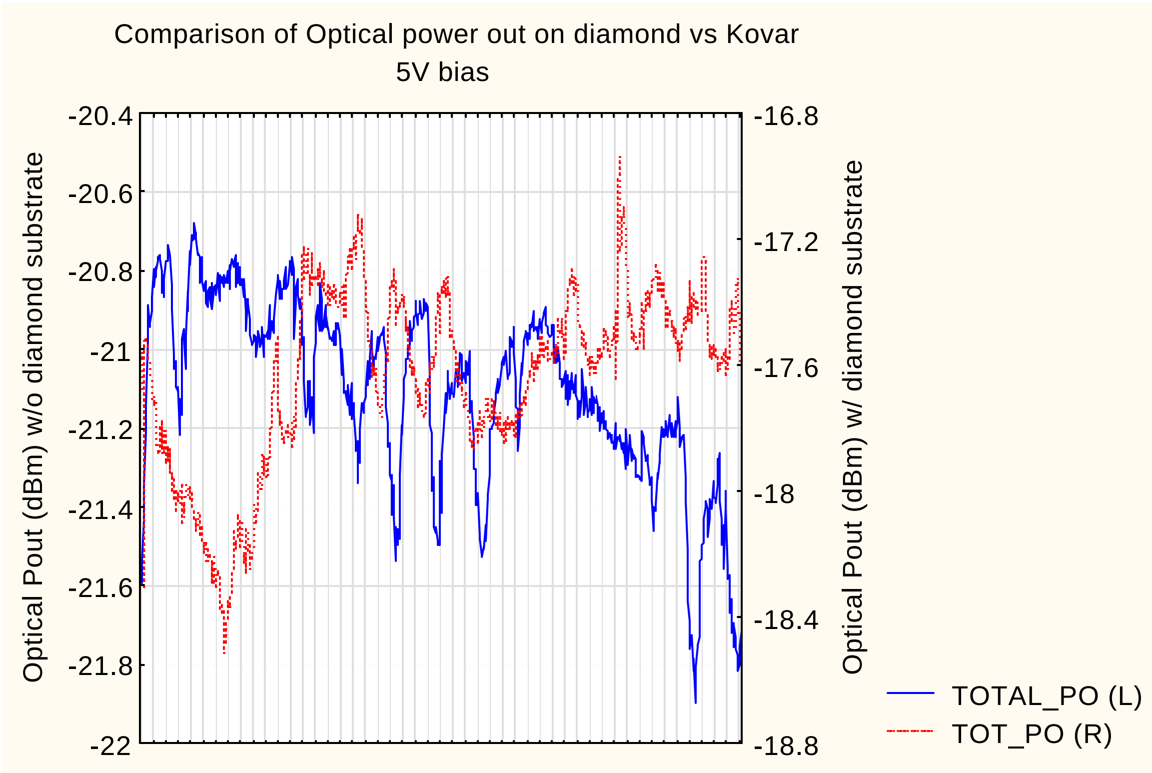

Figure 11. Comparison of Optical power out on diamond vs Kovar substrate

Table 3

Statistical Comparison of Output power data (dBm) for VCSEL mounted to diamond substrate vs Kovar header over the same number of observations

	Observations	Mean Pout	Minimum Pout	Maximum Pout	Variance	Std.Dev.
PEAK_A	674	-21.2620	-22.1000	-20.8000	.058823	.242534
TOTAL_PO	674	-21.1051	-21.8966	-20.6775	.055431	.235438
PEAK_B	674	-17.7111	-18.6000	-17.0000	.084051	.289916
TOT_PO	674	-17.6358	-18.5157	-16.9374	.081063	.284717

PEAK_A = Peak power of primary spectral peak for Kovar mounted sample
TOTAL_PO = Total power output for Kovar mounted sample
PEAK_B = Peak power of primary spectral peak for diamond mounted sample
TOT_PO = Total power out for diamond mounted sample

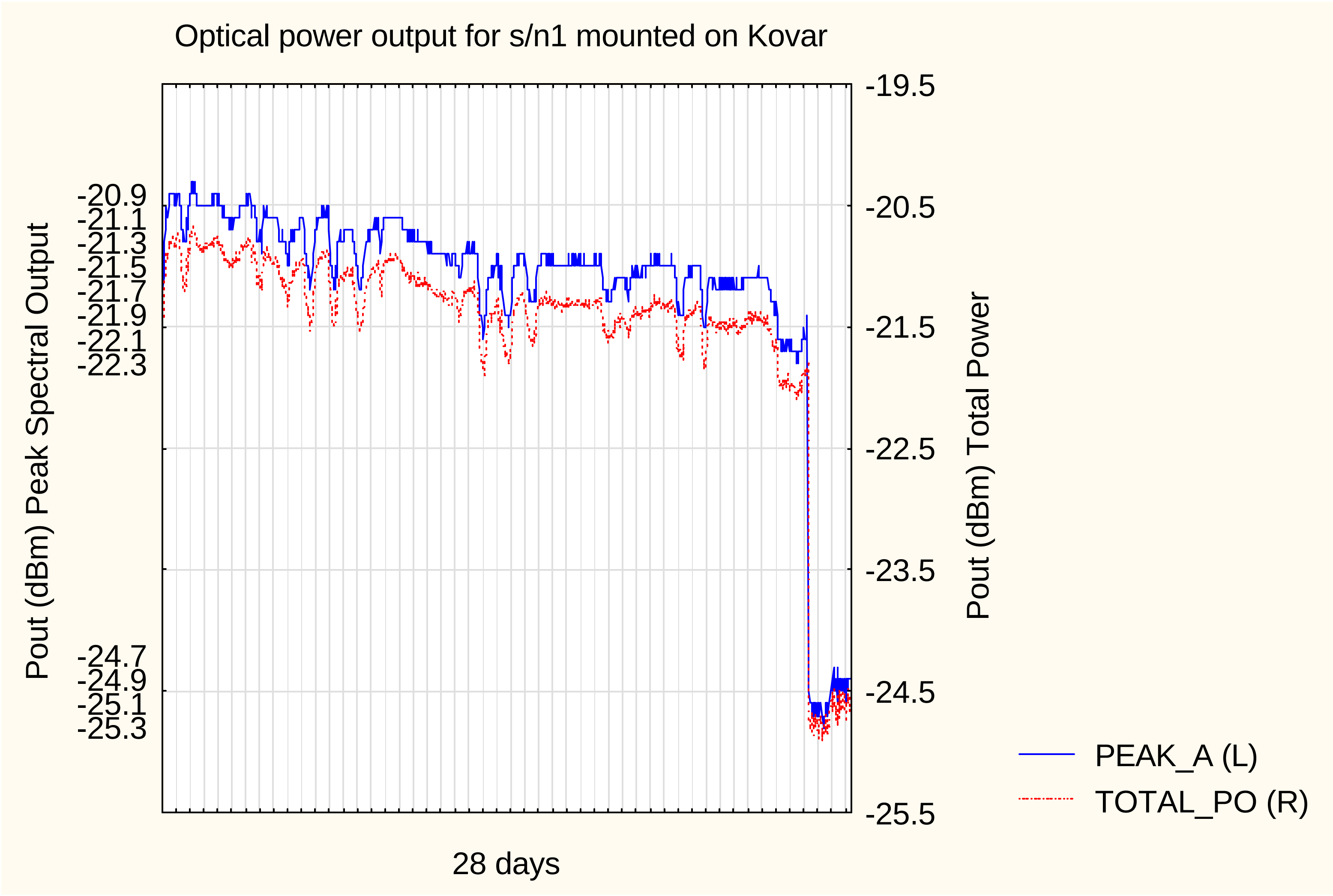

Figure 12. Optical power output for s/n 1 mounted on Kovar

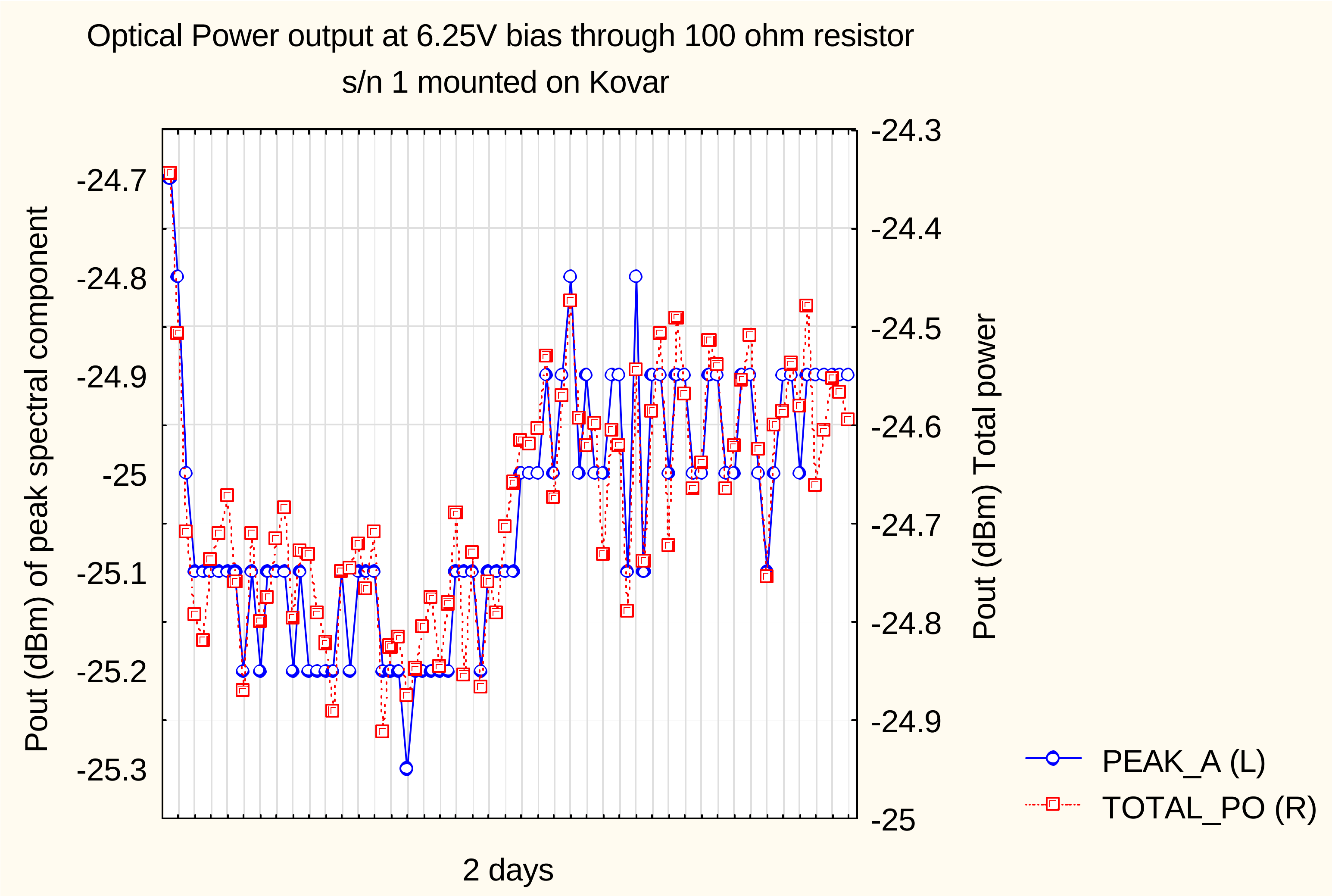

Figure 13. Optical power for S/N 1 at 6.25 V mounted on Kovar

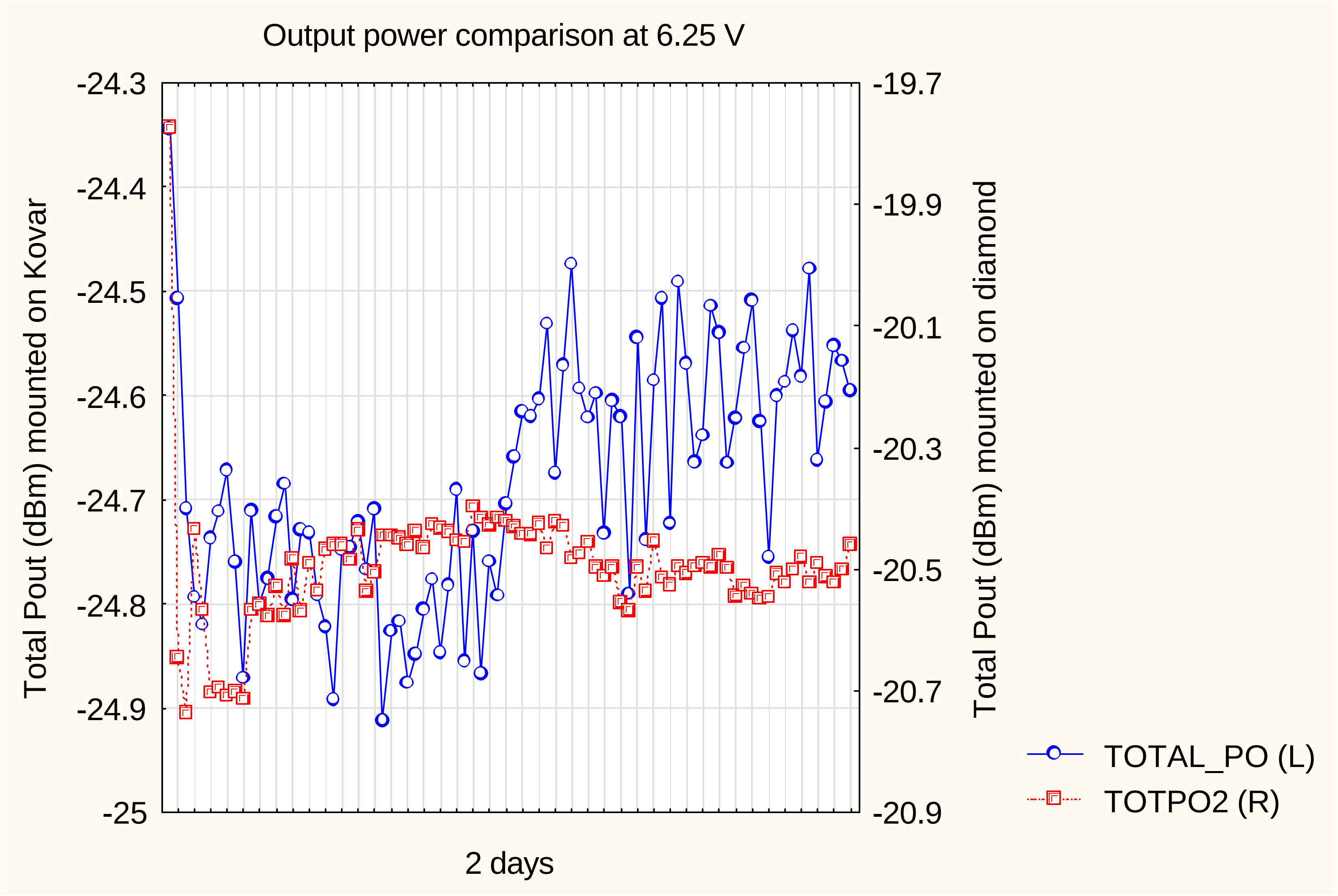

Figure 14. Output power comparison at 6.25 V for diamond and Kovar mounting

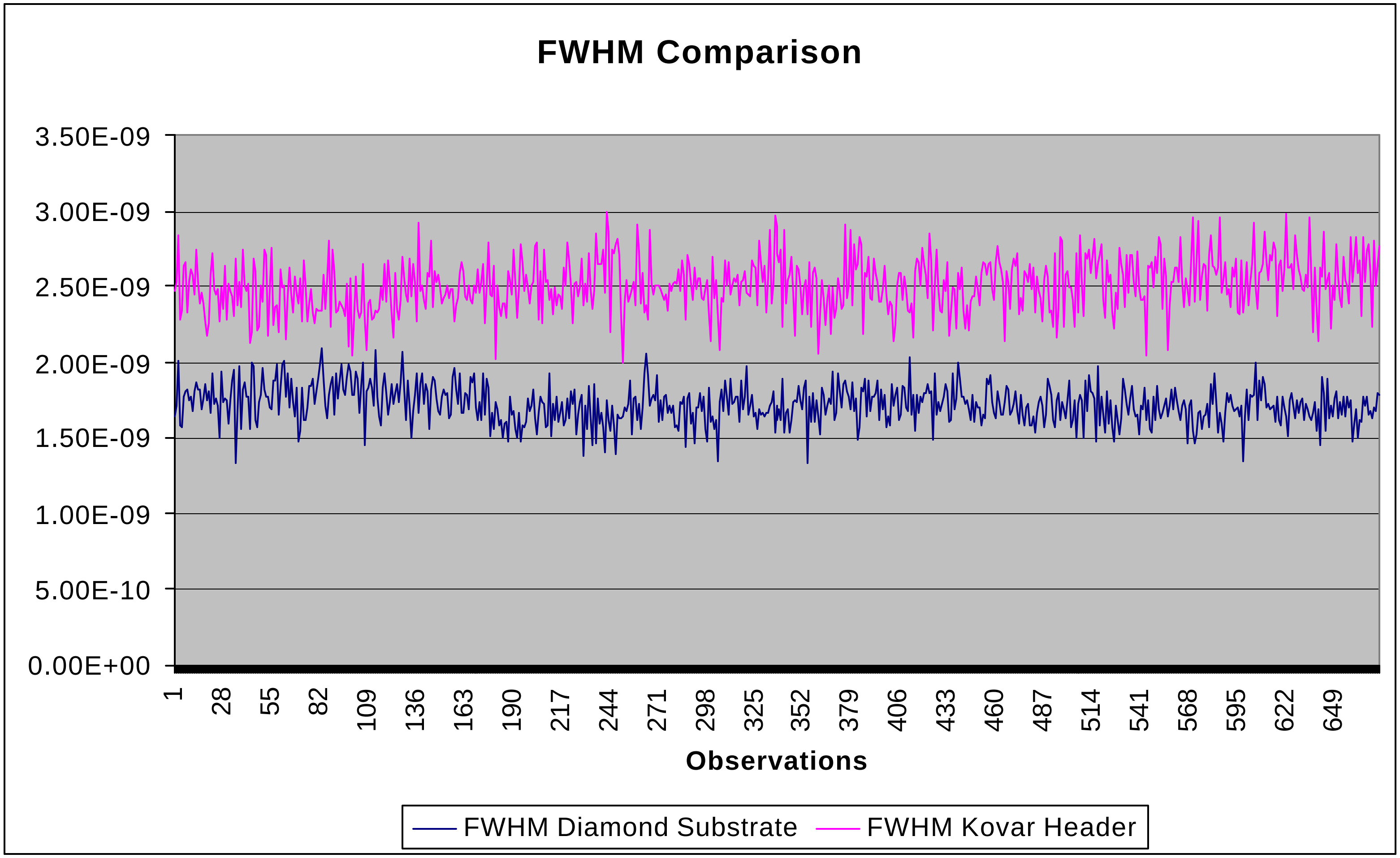

Figure 15. Full Width at Half Max comparison between diamond mounted sample and kovar mounted sample.

FWHM = 2.355 σ

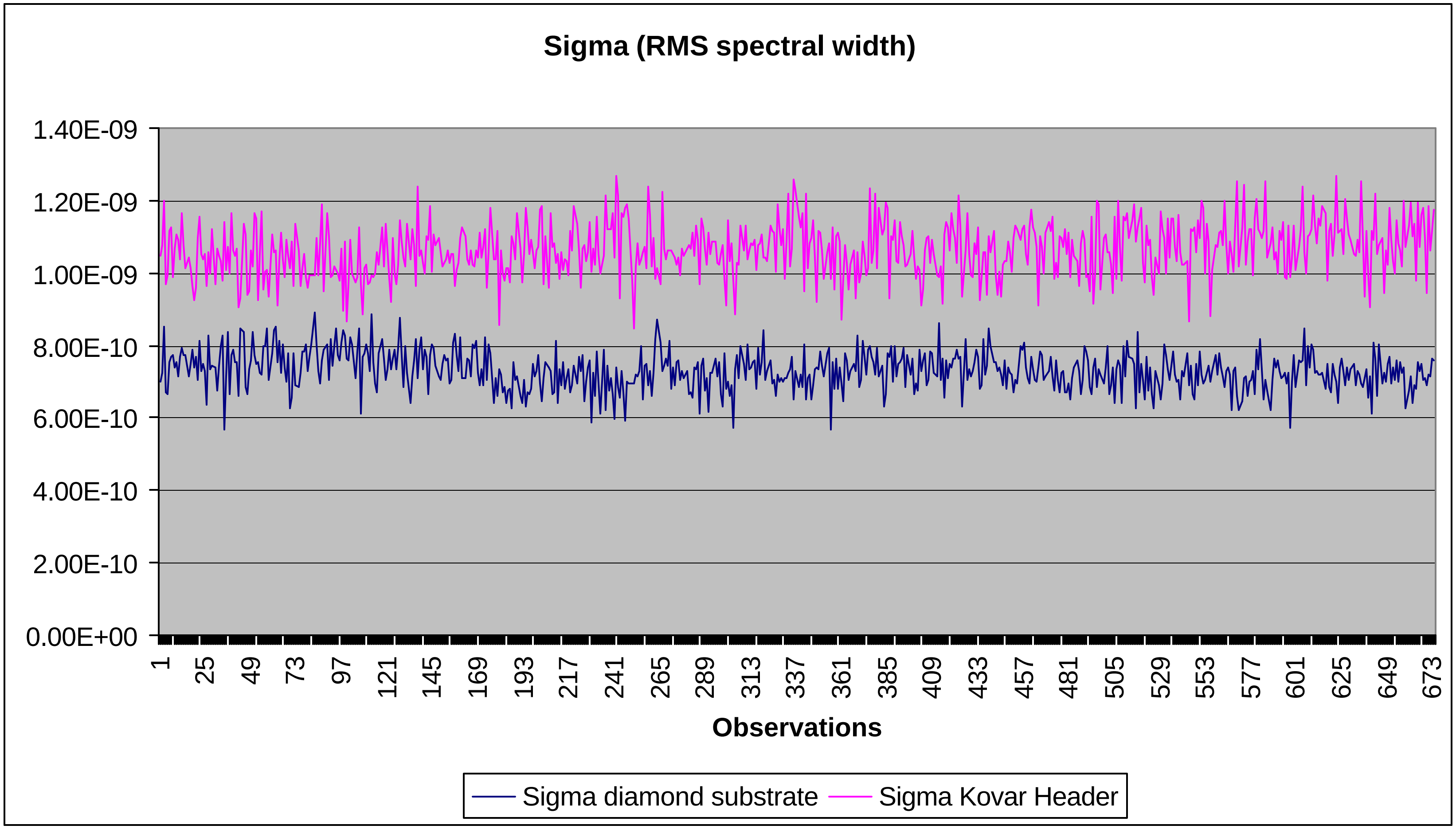

Figure 16. Sigma comparison between diamond mounted sample and kovar mounted sample.

$\sigma = (\Sigma\, P_{i,\ i=1,,n}(\lambda_i - \lambda_{mean})^2/P_{tot})^{0.5}$

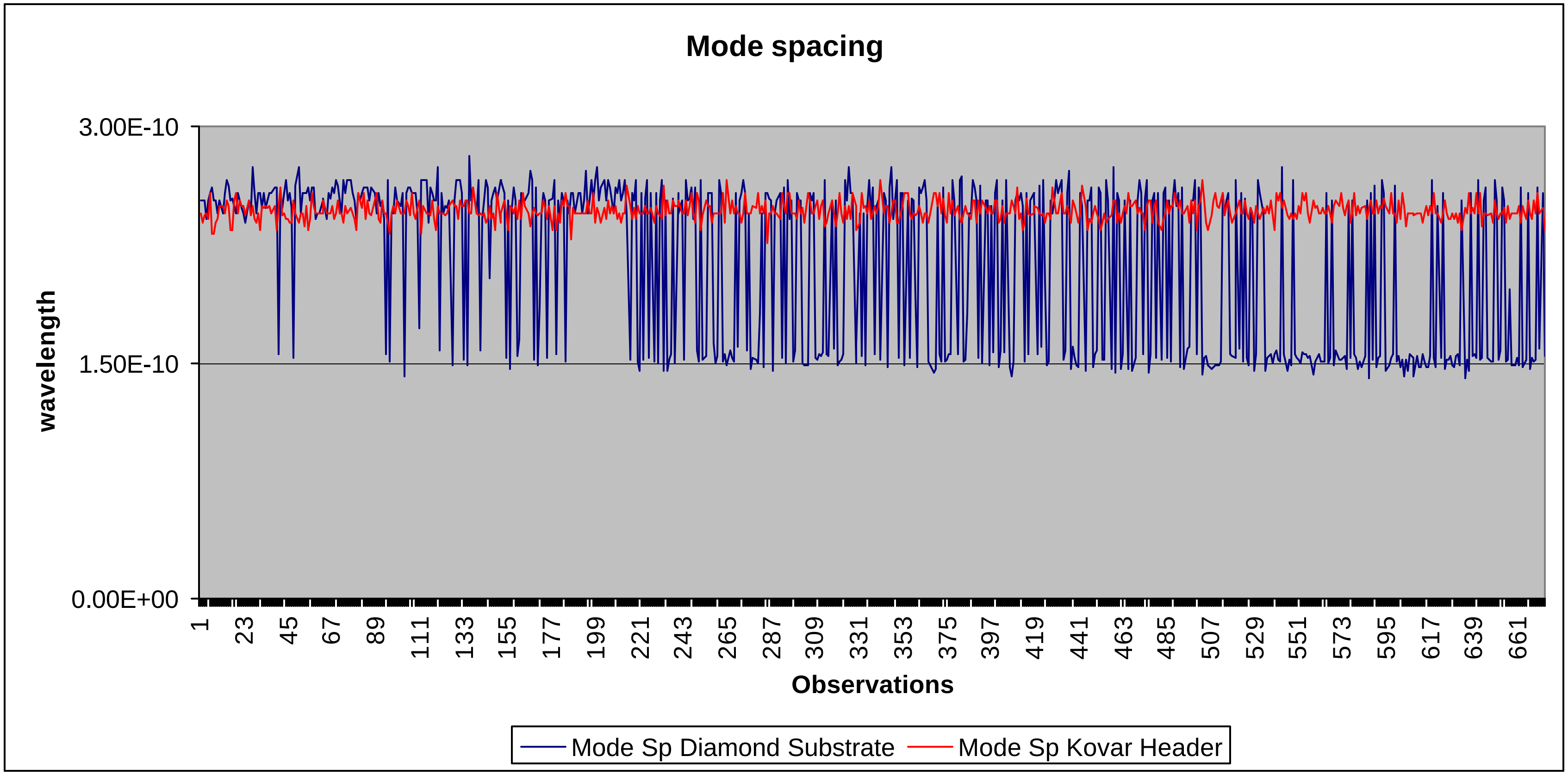

Figure 17. Mode Spacing comparison between diamond mounted sample and kovar header sample.

Mode spacing is the average wavelength spacing between spectral components of the VCSEL